

MID-TERMS ANSWERS

EE 322 FEB 05

① $I_s = I_s (e^{qV_0/kT} - 1)$

$R_{SiO_2} = \sqrt{A_p^2 \rho_p}$

$I_{DC} = 1mA$ $r = \frac{25mV}{I}$

$V_0 = \frac{25 \times 40mV}{11K} = 1mV$

$r = 25\Omega$

$V_0 = 1mV$

②

$r = \frac{25mV}{I}$ $r = 25\Omega$

$A_v = \frac{R_L}{r} = \frac{100}{1} = 100$

$A_i = \beta \frac{r}{R_L} = 100 \times \frac{25}{100} = 25$

$Z_{in} = 25\Omega$

③

$2V = 24K(I_B) + 176K(I_B)$

$2V = 200K I_B$ $I_B = 10\mu A$

$I_C = 2mA$

$V_{CE} = 6.8V$

$I_C = 1mA$

$r = 25\Omega$

$A_v = -100$

$A_i = -100$

$Z_{in} = 2.5K$

④

easy way CHANGE TO T-MODEL

$V_s = I_s 1K + (\beta+1) I_b 10K$

$V_s = I_s (1K + 100K)$

$I_s = \frac{V_s}{100K}$

$V_o = 100K I_b$

$V_o = 10 I_b 100K$

$V_o = 1000K I_b$

$\frac{V_o}{V_s} \approx \frac{\beta I_b R_L}{I_s I_b + (\beta+1) I_b R_E}$

$\frac{V_o}{V_s} \approx 10$

$Z_{in} \approx 100K$